NSN 5962-01-506-3741

Memory Microcircuit - Page 1 of 1





Operating Tempurature Range: -40.0/+125.0 degrees celsius End Application: Used in 1146472g1 Inclosure Configuration: Leaded chip carrier Product Name: 3 volt fast boot block flash memory Voltage Rating And Type Per Characteristic: 2.7 volts input and 3.6 volts input Memory Device Type: Eprom Memory Capacity: Device density x16 (16-mbit), access speed 95ns Terminal Type And Quantity:

56 beam lead

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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